
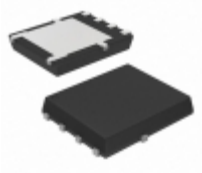
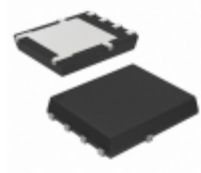
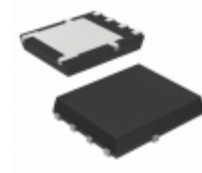


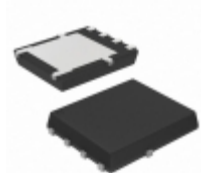
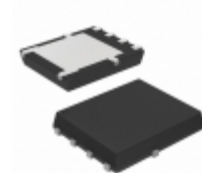
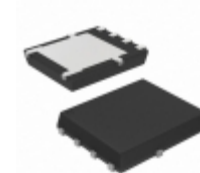
	<h2 style="color: red;">NTMFS4921NT1G</h2>
	<p>Hersteller-Teilenummer: NTMFS4921NT1G</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 30V 8.8A SO8FL</p> <p>Datenblätter:  NTMFS4921NT1G.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 63040 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NTMFS4921NT1G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 30V 8.8A SO8FL
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	63040 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	8-PowerTDFN, 5 Leads
Supplier Device-Gehäuse	5-DFN (5x6) (8-SOFL)
Verlustleistung (max)	870mW (Ta), 38.5W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	8.8A (Ta), 58.5A (Tc)
Rds On (Max) @ Id, Vgs	6.95 mOhm @ 30A, 10V
VGS (th) (Max) @ Id	2.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	25nC @ 11.5V
Eingabekapazität (Ciss) (Max) @ Vds	1400pF @ 12V
Verpackung	Tape & Reel (TR)

NTMFS4921NT1G ist neu im Original, Suche NTMFS4921NT1G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTMFS4921NT1G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTMFS4921NT1G: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>NTMFS4921NT3G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 8.8A SO8FL</p>	 <p>NTMFS4898NFT3G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V SO-8FL</p>	 <p>NTMFS4925NET1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 48A SO8-FL</p>	 <p>NTMFS4921N ON NTMFS4921N ON</p>
 <p>NTMFS4921NT ON ON QFN</p>	 <p>NTMFS4898NFT1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V SO-8FL</p>	 <p>NTMFS4923NET1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 91A SO-8FL</p>	 <p>NTMFS4922NET1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 147A SO8-FL</p>

heiße Teile

Mehr

NTMFS4821NT1G	NTMFS4823NT1G	NTMFS4833NT1G	NTMFS4834N	NTMFS4834NT1G
NTMFS4835N	NTMFS4835NT1G	NTMFS4837NHT1G	NTMFS4837NHT3G	NTMFS4837NT1G
NTMFS4839NHT1G	NTMFS4841NHT1G	NTMFS4841NHT3G	NTMFS4841NT1G	NTMFS4845NT1G
NTMFS4846	NTMFS4846NT1G	NTMFS4847N	NTMFS4847NAT1G	NTMFS4847NT1G
NTMFS4849NT1G	NTMFS4851NT1G	NTMFS4852NT1G	NTMFS4898NFT1G	NTMFS4899NFT1G
NTMFS4921NT3G	NTMFS4923NET1G	NTMFS4925NT1G	NTMFS4925NT3G	NTMFS4926NT1G
NTMFS4927NT1G	NTMFS4933NT1G	NTMFS4934NT1G	NTMFS4935N	NTMFS4935NT1G
NTMFS4936N	NTMFS4936NT1G	NTMFS4937N	NTMFS4937NT1G	NTMFS4939NT1G
NTMFS4939NT3G	NTMFS4941NT1G	NTMFS4943NT1G	NTMFS4945NT1G	NTMFS4946N
NTMFS4946NT1G	NTMFS4955NT1G	NTMFS4982NFT1G	NTMFS4983NBFTG	NTMFS4983NFT1G

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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